

MA4SW510

HMIC[™] Silicon SP5T PIN Diode Switch RoHS Compliant

M/A-COM Products Rev. V4

FEATURES

- Ultra Broad Bandwidth: 50MHz to 26GHz
- 1.0 dB Insertion Loss
- ♦ 30 dB Isolation at 20GHz
- Reliable.
- Fully Monolithic
- Glass Encapsulated Construction
- + +33dBm Input Power

DESCRIPTION

The MA4SW510 is a SP5T Series-Shunt broad band switch made with M/A-COM's ${\rm HMIC}^{\rm TM}$

(Heterolithic Microwave Integrated Circuit) process, US Patent 5,268,310. This process allows the incorporation of silicon pedestals that form series and shunt diodes or vias by imbedding them in a low loss, low dispersion glass. This hybrid combination of Silicon and Glass gives HMIC Switches exceptional low loss and remarkable high isolation through low millimeter-wave frequencies.



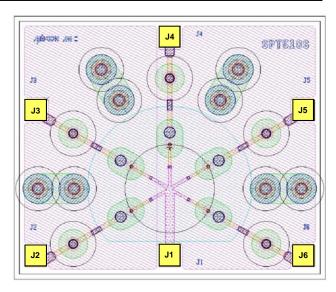
These high performance switches are suitable for the use in multi-band ECM, Radar, and instrumentation control circuits where high isolation to insertion loss ratios are required. With a standard +5V/-5V, TTL controlled PIN diode driver, 50ns switching speeds are achieved.



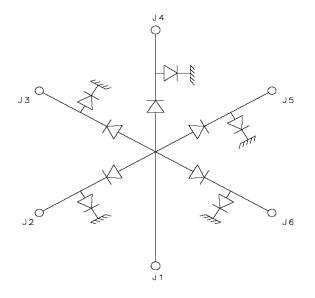
PARAMETER	VALUE
OPERATING TEMPERATURE	- 65°C to +150°C
STORAGE TEMPERATURE	- 65°C to +175°C
RF C.W. INCIDENT POWER	+33dBm
FORWARD BIAS CURRENT	± 20mA
REVERSE APPLIED VOLTAGE	- 25V

Notes:

- 1. Exceeding any one of these values may result in permanent damage to the chip.
- 2. Maximum operating conditions for combination of RF power, D.C. bias and temperature: +30dBm C.W.,



Yellow areas indicate bond pads



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TYPICAL DRIVER CONNECTIONS

CONTROL LEVEL (DC CURRENT)			CONDITION OF RF OUTPUT						
J2	13	J4	J5	J6	J2-J1	J3-J1	J4-J1	J5-J1	J6-J1
-20 mA	+20 mA	+20 mA	+20 mA	+20 mA	Low Loss	Isolation	Isolation	Isolation	Isolation
+20 mA	-20 mA	+20 mA	+20 mA	+20 mA	Isolation	Low Loss	Isolation	Isolation	Isolation
+20 mA	+20 mA	-20 mA	+20 mA	+20 mA	Isolation	Isolation	Low Loss	Isolation	Isolation
+20 mA	+20 mA	+20 mA	-20 mA	+20 mA	Isolation	Isolation	Isolation	Low Loss	Isolation
+20 mA	+20 mA	+20 mA	+20 mA	-20 mA	Isolation	Isolation	Isolation	Isolation	Low Loss

Electrical Specifications @ T_{AMB} = 25°C, ±20mA bias current (on-wafer measurements)

RF SPECIFICATIONS						
PARAMETER	FREQUENCY	MIN.	TYP.	MAX.	UNITS	
INSERTION LOSS	20GHz		0.9	1.4	dB	
ISOLATION	20GHz	28	38		dB	
INPUT RETURN LOSS	20GHz		22		dB	
OUTPUT RETURN LOSS	20GHz		23		dB	
SWITCHING SPEED	10GHz ¹		50		nS	

Note:

1.) Typical switching speed is measured from 10% to 90% of the detected RF voltage driven by a TTL compatible driver. Driver output parallel RC network uses a capacitor between 390pF - 560pF and a resistor between 150Ω - 220Ω to achieve 50ns rise and fall times.

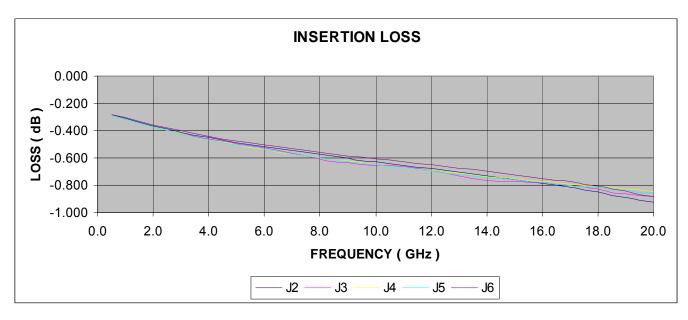
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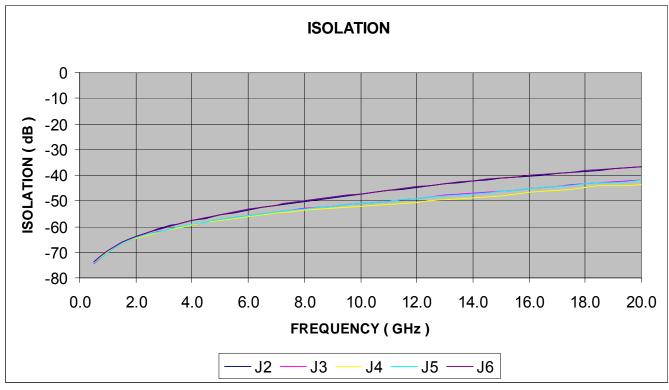
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Typical Microwave Performance





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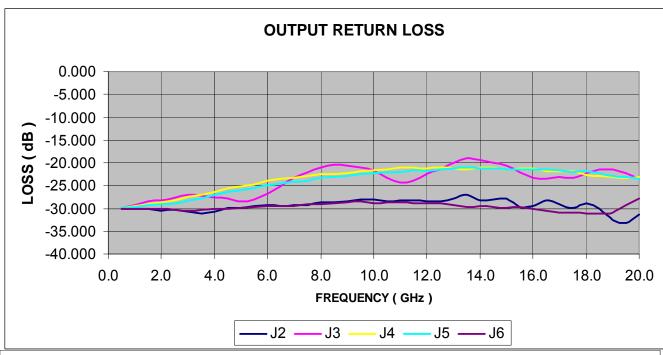
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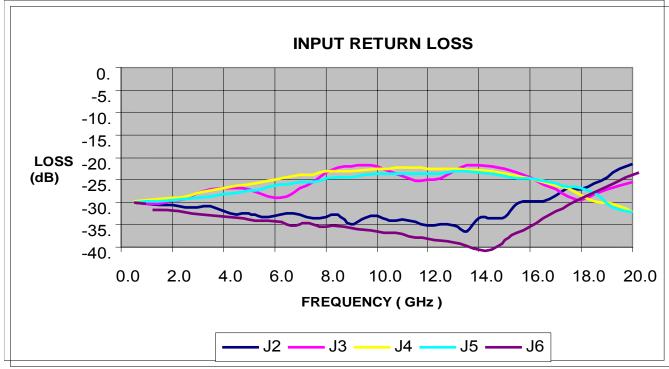
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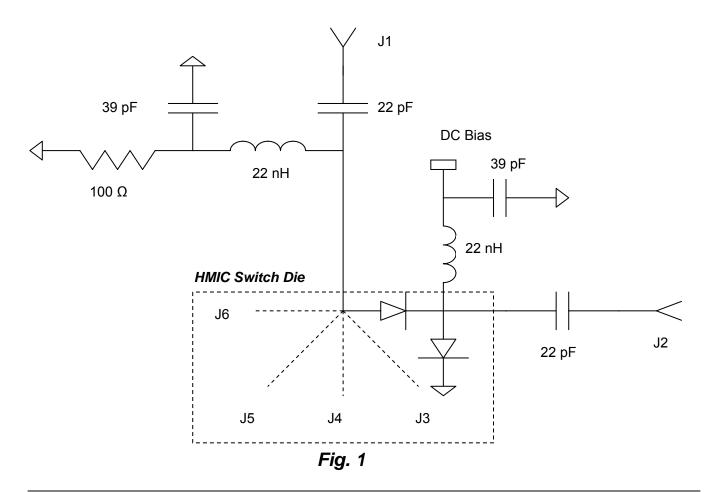
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Operation of the MA4SW510 Switch

The simultaneous application of negative DC current to the Low Loss Port and positive DC current to the remaining Isolated Ports as shown in Figure 1 achieves operation of the MA4SW510 diode switch. The backside area of the die is the RF and DC return ground plane. The DC return is achieved on common Port J1. Constant current sources should supply the DC control currents. The voltages at these points will not exceed ±1.5 volts (1.2 volts typical) for supply currents up to ± 20 mA. In the Low Loss state, the Series Diode must be forward biased and the Shunt Diode reverse biased. For all the isolated ports, the Shunt Diode is forward biased and the Series Diode is reverse biased. The bias network design should yield >30 dB RF to DC isolation. Best Insertion Loss, P1dB, IP3, and switching speed are achieved by using a voltage pull-up resistor in the DC return path, (J1). A minimum value of | -2V | is recommended at this return node, which is achievable with a standard, 65V TTL controlled PIN diode driver. A typical DC bias schematic for 2-18 GHz operation is shown in Figure 1.

2 – 18 GHz Bias Network Schematic



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ASSEMBLY INSTRUCTIONS

Cleanliness

These chips should be handled in a clean environment free of organic contamination.

Electro-Static Sensitivity

The MA4SW510 PIN switch is ESD, Class 1A sensitive (HBM). The proper ESD handling procedures must be used.

Wire Bonding

Thermosonic wedge wire bonding using 0.003" x 0.00025" ribbon or 0.001" diameter gold wire is recommended. A stage temperature of 150°C and a force of 18 to 22 grams should be used. Ultrasonic energy should be adjusted to the minimum required. RF ribbon and wire bonds should be kept as short as possible to minimize parasitic inductance.

Mounting

These chips have Ti-Pt-Au back metal. They can be die mounted with a 80/20, Au/Sn or electrically conductive Ag epoxy. Mounting surface must be flat and clean of oils and contaminants.

Eutectic Die Attachment

An 80/20 gold-tin eutectic solder preform is recommended with a work surface temperature of 255°C and a tool tip temperature of 265°C. When hot gas is applied, the tool tip temperature should be 290°C. The chip should not be exposed to temperatures greater than 320°C for more than 10 seconds. No more than 3 seconds should be required for the die attachment.

Silver Epoxy Die Attachment

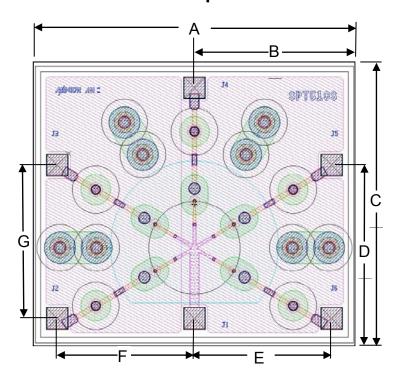
Assembly should be preheated to 125°C-150°C. A controlled thickness of 2 mils is recommended for best electrical and thermal conductivity. A thin epoxy fillet should be visible around the perimeter of the chip after placement to ensure complete coverage. Cure epoxy per manufacturer's recommended schedule.

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MA4SW510 Chip Dimensions



Chip Dimensions*

DIM	INCHES	μM
А	0.0680	1723
В	0.0340	858
С	0.0580	1473
D	0.0370	938
Е	0.0295	750
F	0.0295	750
G	0.0325	825
All Pads	.005 X .005	120 X 120
Thickness	0.005	127

^{*}All chip dimension tolerances are ±.0005"

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